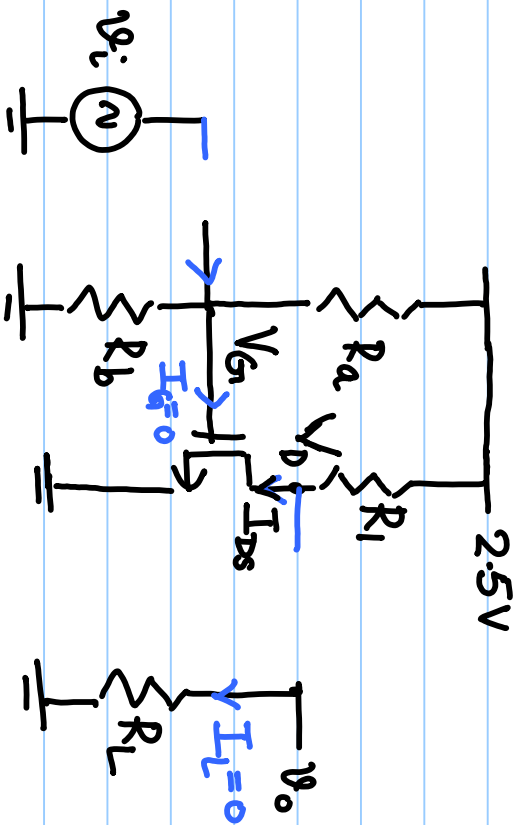
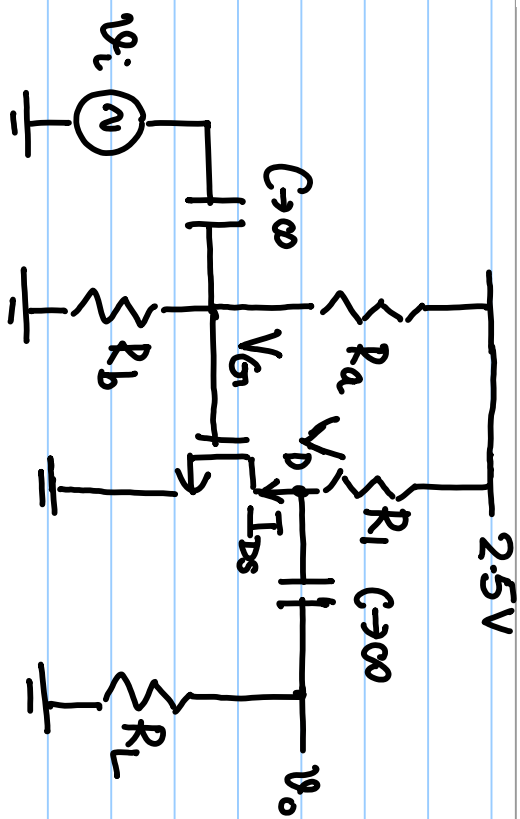


lecture # 10



$R_a = 5.2k, R_b = 4.0k, R_1 = 4k, R_L = 4k$

$V_{th} = 0.7V, \mu_n C_{ox} = 100 \mu A/V^2, \frac{W}{L} = 20$

DC Operating point:

$I_{GS} = 0$

$V_{GS} = \frac{R_b}{R_b + R_a} \times 2.5V = \frac{4.8k}{10k} \times 2.5 = 1.2V$

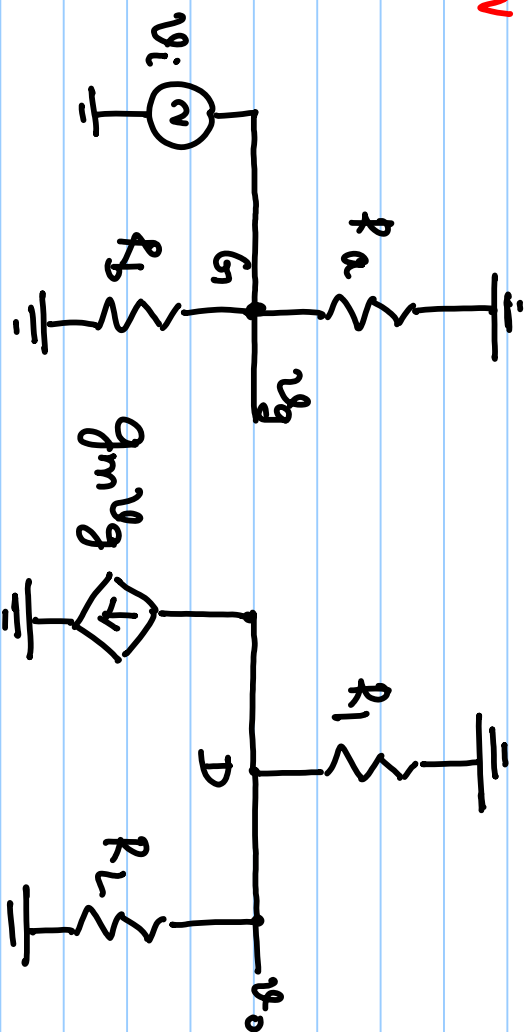
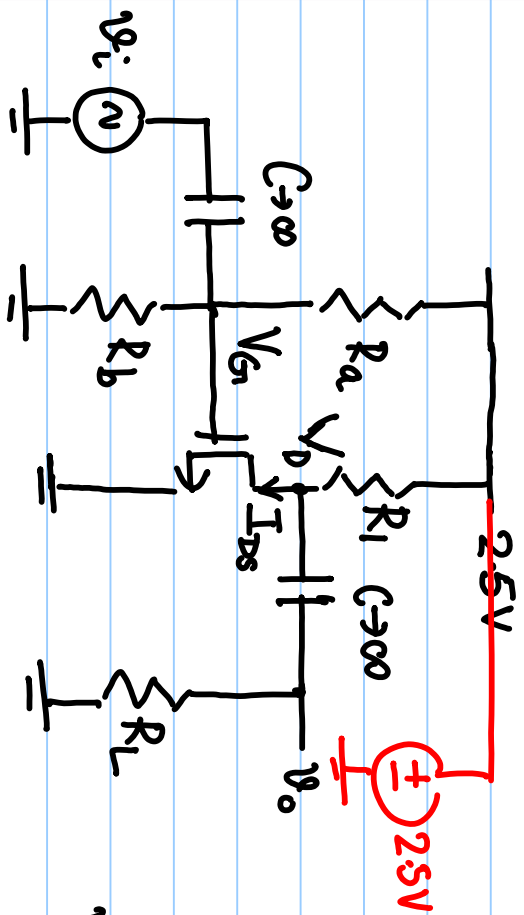
$I_{DS} = \frac{\mu_n C_{ox}}{2} \frac{W}{L} (V_{GS} - V_{th})^2$

$= \frac{100 \times 10^{-6}}{2} \times 20 (1.2 - 0.7)^2$
 $= 1 mA/V^2 \times 0.25 = 0.25 mA$

$V_{DS} = 2.5 - I_{DS} \times R_1 = 2.5 - 4k \times 0.25 mA$
 $= \underline{1.5V}$

$$V_{GS} - V_{th} = 1.2 - 0.7 = 0.5 < V_{DS} \quad \checkmark$$

AC Small-signal gain.

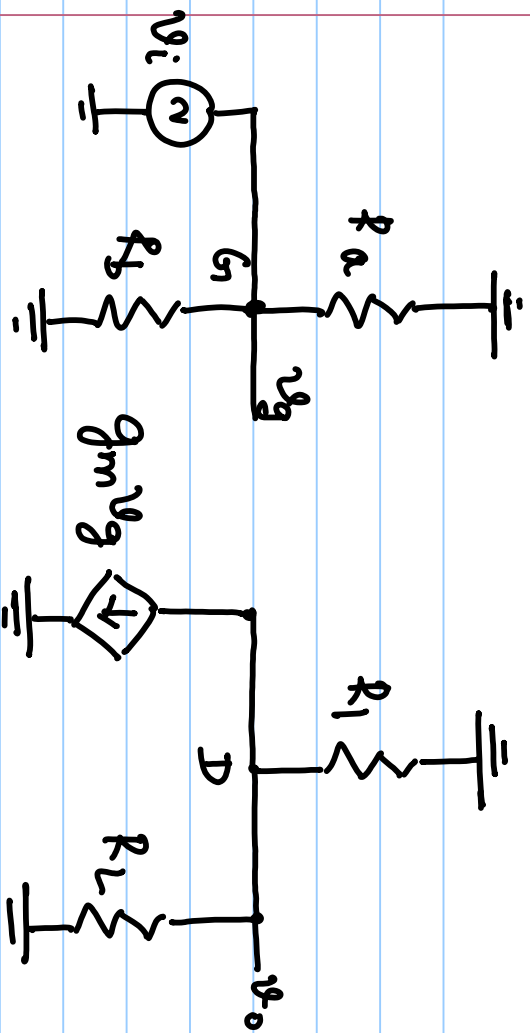


$$\frac{1}{sC} = \frac{1}{j\omega C}$$

All independent voltage sources are shorted.

If MOSFET is in linear region.

$$I_{DS} = \mu_n C_{ox} \frac{W}{L} \left[(V_{GS} - V_{th}) V_{DS} - \frac{V_{DS}^2}{2} \right] = \frac{V_{DD} - V_{DS}}{R_1}$$

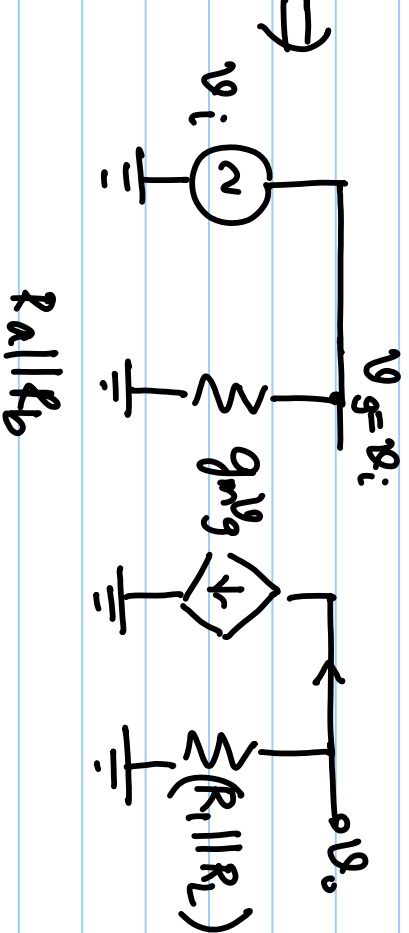


$$v_o = -(g_m v_i) (R_1 || R_L)$$

$$\frac{v_o}{v_i} = -g_m (R_1 || R_L)$$

$$= -1 \text{ mA/V} \times 2 \text{ k}\Omega$$

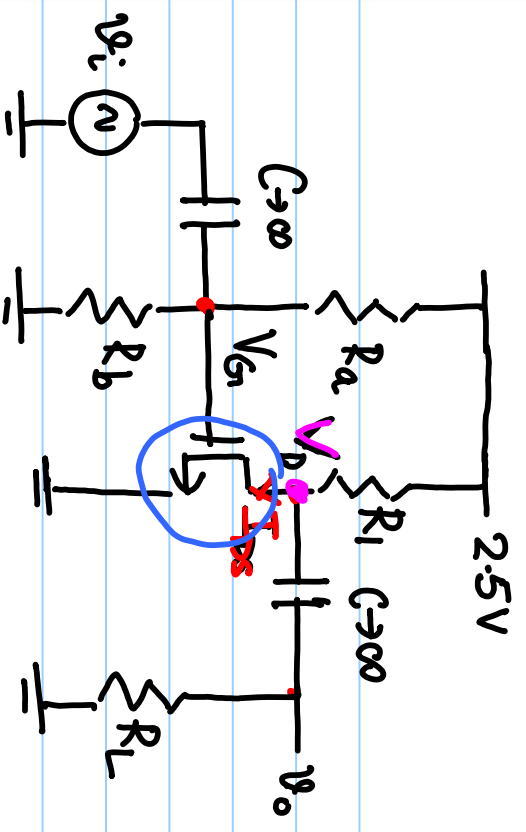
$$= -2 \text{ V/V}$$



$$g_m = \frac{2I_{DQ}}{V_{GS} - V_{th}} = \frac{2 \times 0.25 \text{ mA}}{0.5 \text{ V}}$$

$$= 1 \text{ mA/V}$$

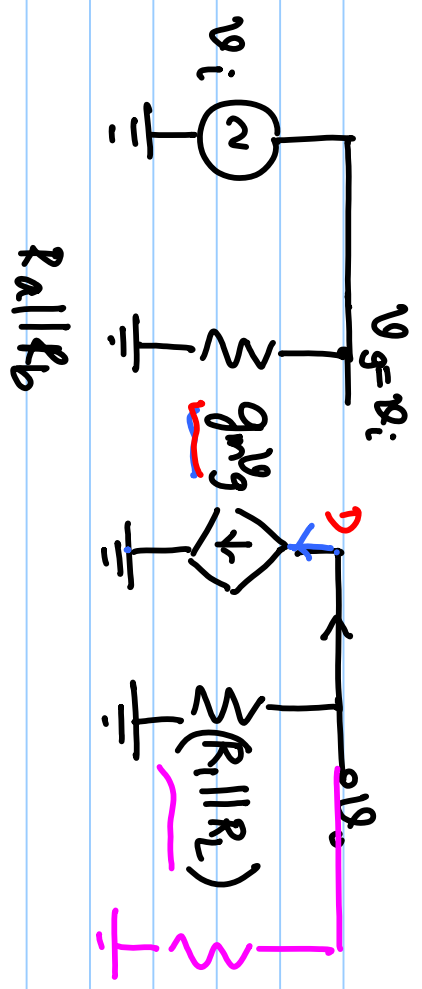
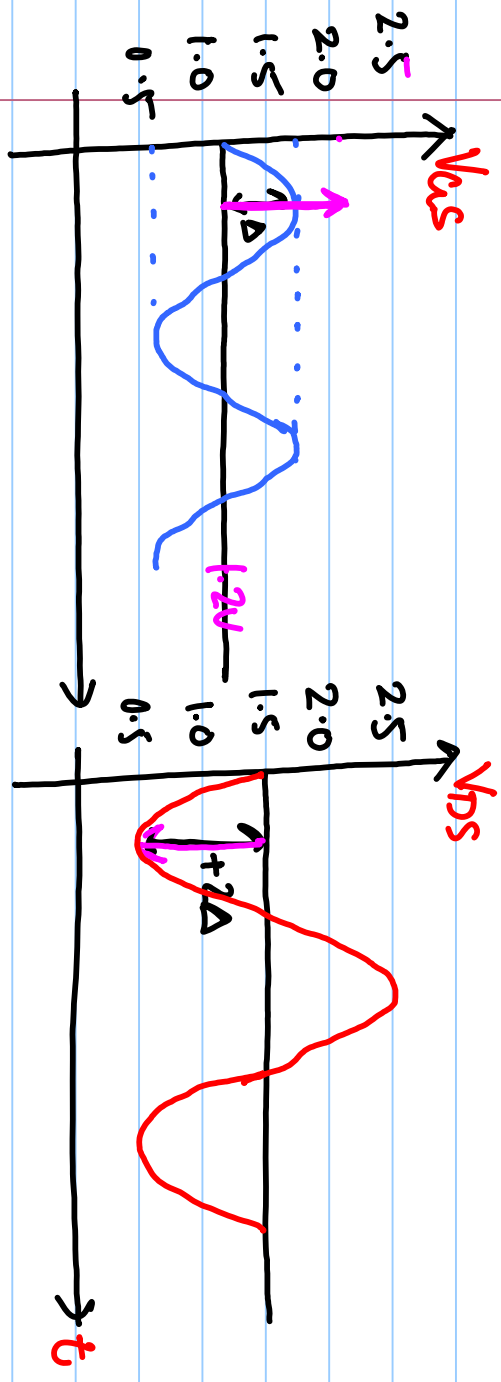
$$R_1 || R_L = (4 \text{ k} || 4 \text{ k}) = 2 \text{ k}\Omega$$



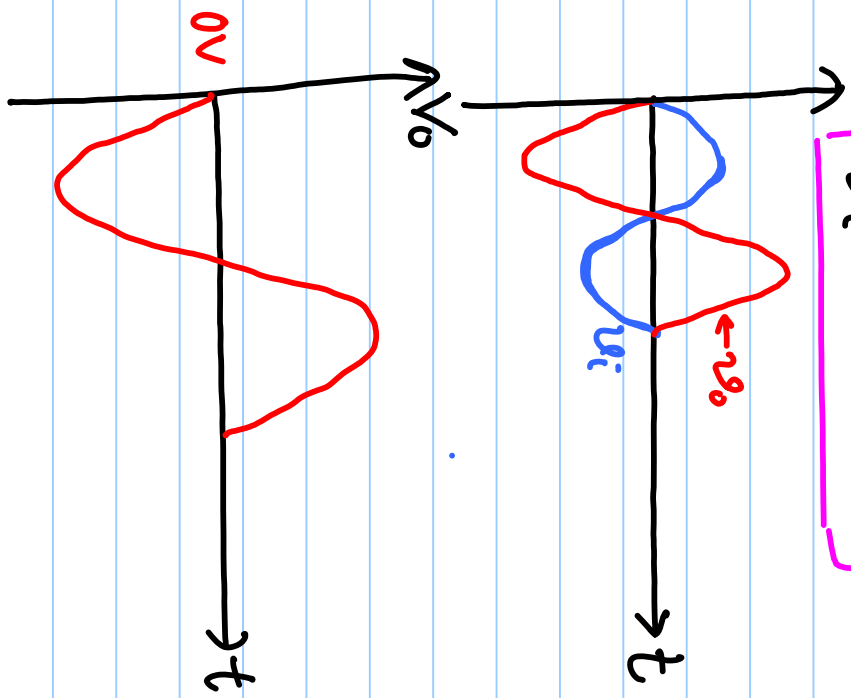
Absolute voltage.

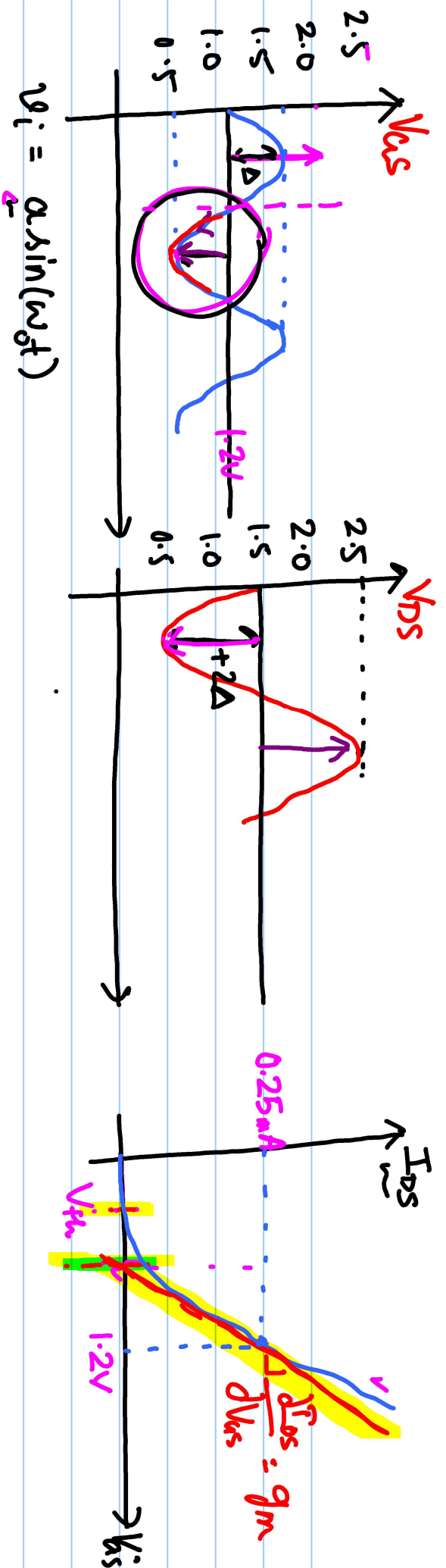
$$V_{GS} = 1.2V + v_i$$

$$V_{DS} = 1.5V + v_o$$



$$\frac{v_o}{v_i} = -2V/V$$





$$V_{GS} = 1.2V + a$$

$$V_{DS} = 1.5 - 2a$$

- Transistor always operates in saturation region.

$$V_{GS} \geq V_{GS} - V_{th} \Rightarrow 1.5 - 2a \geq 1.2 + a - 0.7 \Rightarrow 1.0 \geq 3a \Rightarrow$$

$$\boxed{a \leq \frac{1}{3} = 0.333V}$$

$$- \checkmark V_{GS} - V_{th} \geq 0 \Rightarrow 1.2 - a - 0.7 \geq 0 \Rightarrow a \leq 0.5V \checkmark$$

$$- I_{DS} = 0.25 \text{ mA} + g_m a = 0$$

$$0.25 \text{ mA} - g_m a \geq 0$$

$$a \leq \frac{0.25 \text{ mA}}{1 \text{ mA/V}} \Rightarrow \boxed{a \leq 0.25V}$$

